

Features

- · Optimized Body Diode Reverse Recovery Performance
- · Low On-resistance and Low Conduction Losses
- Ultra Low Gate Charge Cause Lower Driving Requirement
- Epoxy Meets UL 94 V-0 Flammability Rating
- · Halogen Free. "Green" Device (Note 1)
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings

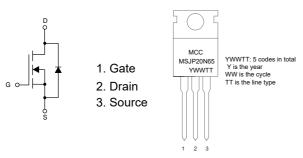
- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 0.83°C/W Junction to Case

Parameter		Symbol	Rating	Unit
Drain-Source Voltage		V _{DS}	650	V
Gate-Source Volltage		V _{GS}	±30	V
Continuous Drain Current	T _C =25°C		20	Α
	T _C =100°C	– I _D	12	Α
Pulsed Drain Current (Note 2)		I _{DM}	60	Α
Single Pulse Avalanche Energy (Note 3)		E _{AS}	484	mJ
Repetitive Avalanche Energy		E _{AR}	0.7	mJ
Avalanche Current		I _{AR}	3.5	Α
Total Power Dissipation		P _D	151	W

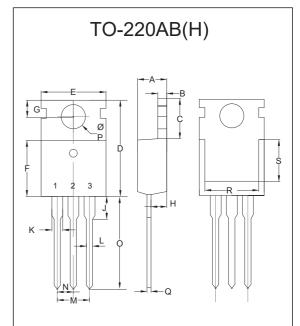
Note:

- Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 2. Repetitive Rating; Pulse Width Limited by Maximum Junction Temperature.
- 3. I_{AS} =3.5A, V_{DD} =50V, R_{G} =25 Ω , Starting T_{J} =25 $^{\circ}$ C.

Internal Structure and Marking Code



N-CHANNEL Super-Junction Power MOSFET



DIMENSIONS						
DIM	INCHES		MM		NOTE	
DIIVI	MIN	MAX	MIN	MAX	NOTE	
Α	0.172	0.188	4.37	4.77		
В	0.049	0.057	1.25	1.45		
С	0.246	0.270	6.25	6.85		
D	0.594	0.634	15.10	16.10		
E	0.382	0.406	9.70	10.30		
F	0.346	0.370	8.80	9.40		
G	0.102	0.118	2.60	3.00		
Н	0.087	0.102	2.20	2.60		
J		0.134		3.40		
K	0.046	0.058	1.17	1.47		
L	0.028	0.037	0.70	0.95		
М	0.200		5.08		TYP.	
N	0.100		2.54		TYP.	
0	0.502	0.543	12.75	13.80		
Р	0.134	0.150	3.40	3.80	Ф	
Q	0.016	0.026	0.40	0.65		
R	0.276		7.00			
S	0.217		5.50			



Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =250μA	650			V
Gate-Source Leakage Current	I _{GSS}	V_{DS} =0V, V_{GS} =±30V			±100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =650V, V _{GS} =0V, T _C =25°C			1	μΑ
		V _{DS} =650V, V _{GS} =0V, T _C =125°C			100	
Gate-Threshold Voltage (Note 4)	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_D=250\mu A$	2.5		4.5	V
Drain-Source On-Resistance (Note 4)	R _{DS(on)}	V _{GS} =10V, I _D =10A		150	180	mΩ
Gate Resistance (Note 4)	R _G	f = 1.0MHz Open Drain		12		Ω
Dynamic Characteristics (Note 5)					
Input Capacitance	C _{iss}			1724		
Output Capacitance	C _{oss}	V_{DS} =100V, V_{GS} =0V,f=1MHz		61		pF
Reverse Transfer Capacitance	C _{rss}			6		
Total Gate Charge	Qg			39		
Gate-Source Charge	Q_{gs}	V_{DS} =520V, V_{GS} =10V, I_{D} =20A		8		nC
Gate-Drain Charge	Q_{gd}			15		
Turn-On Delay Time	t _{d(on)}			15		
Turn-On Rise Time	t _r	V _{DD} =400V,I _D =20A		59		
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10V, R_{GEN} =25 Ω		121		ns
Turn-Off Fall Time	t _f			44		
Drain-Source Diode Character	ristics		<u>'</u>	•		
Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =20A			1.2	V
Continuous Body Diode Current	Is				20	Α
Reverse Recovery Time	t _{rr}			423		ns
Reverse Recovery Charge	Q _{rr}	$V_R = 400V, I_F = I_S,$ $di_F / dt = 100A / \mu s$		5.3		μC
Peak Reverse Recovery Current	I _{rrm}	a.p. a.c 1007 t po		25		Α

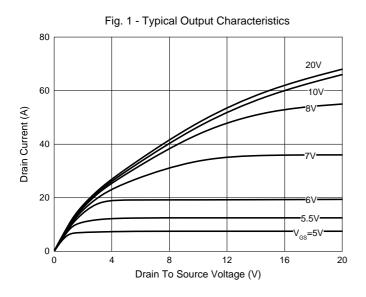
Note:

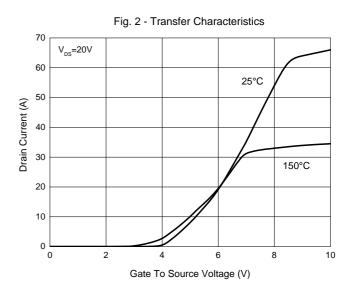
^{4.} Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 1% .

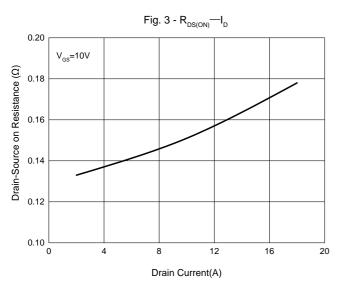
^{5.} Guaranteed by Design, not Subject to Production.

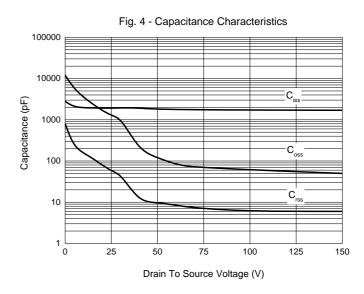


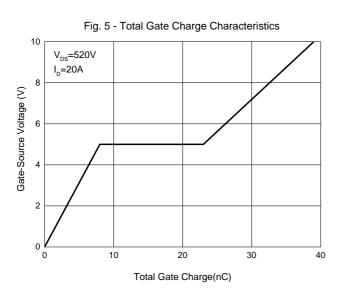
Curve Characteristics

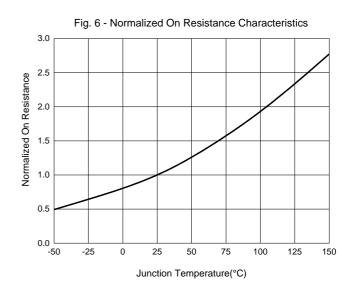














Ordering Information

Device	Packing
Part Number-BP	Bulk:50pcs/Tube,1Kpcs/Box,5Kpcs/Carton

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